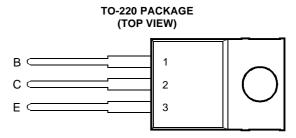
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- Designed for Complementary Use with TIP125, TIP126 and TIP127
- 65 W at 25°C Case Temperature
- 5 A Continuous Collector Current
- Minimum h<sub>FE</sub> of 1000 at 3 V, 3 A



Pin 2 is in electrical contact with the mounting base.

MDTRACA

#### absolute maximum ratings at 25°C case temperature (unless otherwise noted)

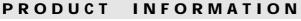
RATING			VALUE	UNIT
	TIP120		60	
Collector-base voltage $(I_E = 0)$	TIP121	V <sub>CBO</sub>	80	V
	TIP122		100	
	TIP120		60	
Collector-emitter voltage ( $I_B = 0$ )	TIP121	V <sub>CEO</sub>	80	V
	TIP122		100	
Emitter-base voltage			5	V
Continuous collector current			5	A
Peak collector current (see Note 1)			8	A
Continuous base current			0.1	A
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)			65	W
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3)			2	W
Unclamped inductive load energy (see Note 4)			50	mJ
Operating junction temperature range			-65 to +150	°C
Storage temperature range			-65 to +150	°C
Lead temperature 3.2 mm from case for 10 seconds			260	°C

NOTES: 1. This value applies for  $t_p \leq 0.3$  ms, duty cycle  $\leq 10\%.$ 

2. Derate linearly to 150°C case temperature at the rate of 0.52 W/°C.

3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.

4. This rating is based on the capability of the transistor to operate safely in a circuit of: L = 20 mH,  $I_{B(on)}$  = 5 mA,  $R_{BE}$  = 100  $\Omega$ ,  $V_{BE(off)}$  = 0,  $R_S$  = 0.1  $\Omega$ ,  $V_{CC}$  = 20 V.





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#### electrical characteristics at 25°C case temperature

PARAMETER			TEST CONDITIONS			TYP	MAX	UNIT
M	Collector-emitter	L 20 m A		TIP120	60 00			V
V <sub>(BR)CEO</sub>	breakdown voltage	I <sub>C</sub> = 30 mA (see Note 5)	I <sub>B</sub> = 0	TIP121 TIP122	80 100			v
I <sub>CEO</sub>	Collector-emitter cut-off current	V <sub>CE</sub> = 30 V	I <sub>B</sub> = 0	TIP120			0.5	
		$V_{CE} = 40 V$	I <sub>B</sub> = 0	TIP121			0.5	mA
		$V_{CE} = 50 V$	I <sub>B</sub> = 0	TIP122			0.5	
I <sub>CBO</sub>	Collector cut-off current	V <sub>CB</sub> = 60 V	I <sub>E</sub> = 0	TIP120			0.2	
		V <sub>CB</sub> = 80 V	$I_E = 0$	TIP121			0.2	mA
		V <sub>CB</sub> = 100 V	$I_E = 0$	TIP122			0.2	
I <sub>EBO</sub>	Emitter cut-off current	V <sub>EB</sub> = 5 V	$I_{\rm C} = 0$				2	mA
h	Forward current	V <sub>CE</sub> = 3 V	I <sub>C</sub> = 0.5 A	(see Notes 5 and 6)	1000			
h <sub>FE</sub>	transfer ratio	$V_{CE} = 3 V$	I <sub>C</sub> = 3 A		1000			
V <sub>CE(sat)</sub>	Collector-emitter	I <sub>B</sub> = 12 mA	I <sub>C</sub> = 3 A	(see Notes 5 and 6)			2	V
	saturation voltage	I <sub>B</sub> = 20 mA	I <sub>C</sub> = 5 A				4	v
$V_{BE}$	Base-emitter	V <sub>CE</sub> = 3 V	V I <sub>C</sub> = 3 A	(see Notes 5 and 6)			2.5	V
	voltage	VCE - UV					2.0	v
$V_{\text{EC}}$	Parallel diode forward voltage	I <sub>E</sub> = 5 A	I <sub>B</sub> = 0	(see Notes 5 and 6)			3.5	V

NOTES: 5. These parameters must be measured using pulse techniques,  $t_p$  = 300  $\mu s,$  duty cycle  $\leq$  2%.

6. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

#### thermal characteristics

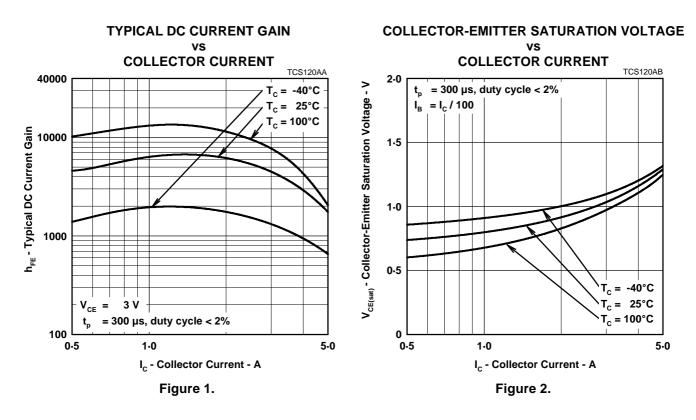
PARAMETER			ТҮР	MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			1.92	°C/W
$R_{\thetaJA}$	Junction to free air thermal resistance			62.5	°C/W

#### resistive-load-switching characteristics at 25°C case temperature

	PARAMETER	TEST CONDITIONS <sup>†</sup>			MIN	ТҮР	MAX	UNIT
t <sub>on</sub>	Turn-on time	I <sub>C</sub> = 3 A	I <sub>B(on)</sub> = 12 mA	I <sub>B(off)</sub> = -12 mA		1.5		μs
t <sub>off</sub>	Turn-off time	V <sub>BE(off)</sub> = -5 V	$R_L = 10 \ \Omega$	$t_p$ = 20 µs, dc $\leq$ 2%		8.5		μs

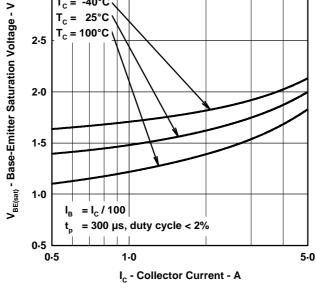
<sup>†</sup> Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

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#### **TYPICAL CHARACTERISTICS**

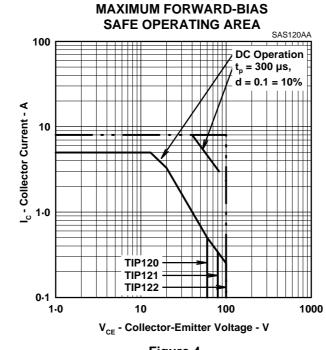
**BASE-EMITTER SATURATION VOLTAGE** vs **COLLECTOR CURRENT** TCS120AC 3.0 -40°C T<sub>c</sub> =  $T_c = 25^{\circ}C$ T<sub>c</sub> = 100°C 2.5







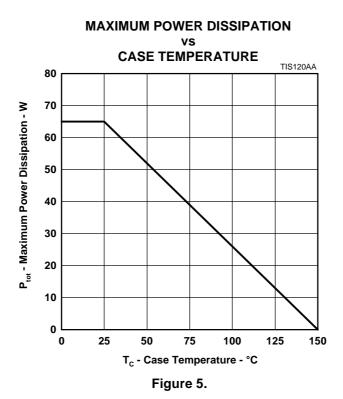
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#### MAXIMUM SAFE OPERATING REGIONS







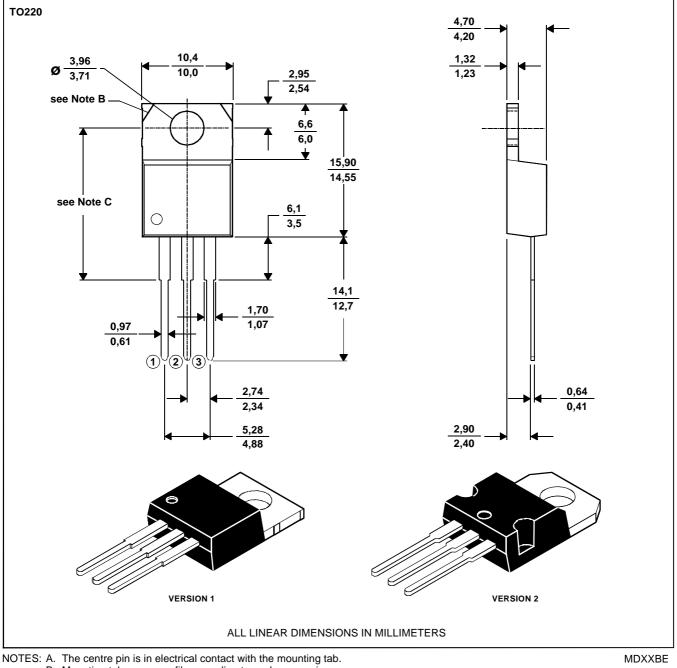
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## **MECHANICAL DATA**

## TO-220

#### 3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



B. Mounting tab corner profile according to package version.

C. Typical fixing hole centre stand off height according to package version.

Version 1, 18.0 mm. Version 2, 17.6 mm.

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